

2SB0950, 2SB0950A (2SB950, 2SB950A)

Silicon PNP epitaxial planar type Darlington

For power amplification and switching

Complementary to 2SD1276 and 2SD1276A

■ Features

- High forward current transfer ratio h_{FE}
- High-speed switching
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25^\circ\text{C}$

Parameter		Symbol	Rating	Unit
Collector to base voltage	2SB0950	V_{CBO}	-60	V
	2SB0950A		-80	
Collector to emitter voltage	2SB0950	V_{CEO}	-60	V
	2SB0950A		-80	
Emitter to base voltage		V_{EBO}	-5	V
Peak collector current		I_{CP}	-8	A
Collector current		I_C	-4	A
Collector power dissipation	$T_C = 25^{\circ}\text{C}$	P_C	40	W
	$T_a = 25^{\circ}\text{C}$		2	
Junction temperature		T_j	150	$^{\circ}\text{C}$
Storage temperature		T_{stg}	-55 to +150	$^{\circ}\text{C}$

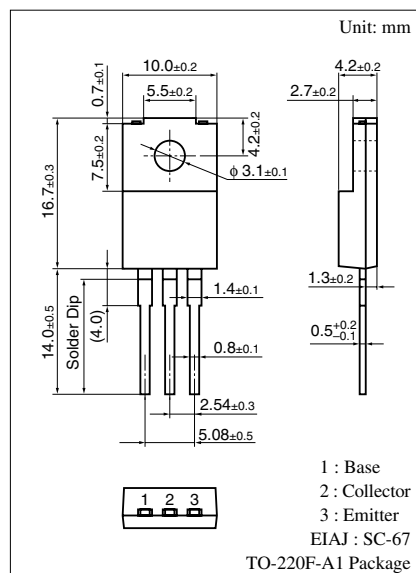
■ Electrical Characteristics $T_C = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector cutoff current	2SB0950 2SB0950A	I_{CBO} $V_{CB} = -60\text{ V}, I_E = 0$			-200	μA
					-200	
Collector cutoff current	2SB0950 2SB0950A	I_{CEO} $V_{CE} = -30\text{ V}, I_B = 0$			-500	μA
					-500	
Emitter cutoff current	I_{EBO}	$V_{EB} = -5\text{ V}, I_C = 0$			-2	mA
Collector to emitter voltage	2SB0950 2SB0950A	V_{CEO} $I_C = -30\text{ mA}, I_B = 0$	-60			V
			-80			
Forward current transfer ratio	h_{FE1} h_{FE2}^*	$V_{CE} = -3\text{ V}, I_C = -0.5\text{ A}$	1 000			
			2 000		10 000	
Base to emitter voltage	V_{BE}	$V_{CE} = -3\text{ V}, I_C = -3\text{ A}$			-2.5	V
Collector to emitter saturation voltage	$V_{CE(sat)1}$ $V_{CE(sat)2}$	$I_C = -3\text{ A}, I_B = -12\text{ mA}$			-2	V
					-4	
Transition frequency	f_T	$V_{CE} = -10\text{ V}, I_C = -0.5\text{ A}, f = 1\text{ MHz}$		20		MHz
Turn-on time	t_{on}	$I_C = -3\text{ A}, I_{B1} = -12\text{ mA}, I_{B2} = 12\text{ mA}, V_{CC} = -50\text{ V}$		0.3		μs
Storage time	t_{stg}			2		μs
Fall time	t_f			0.5		μs

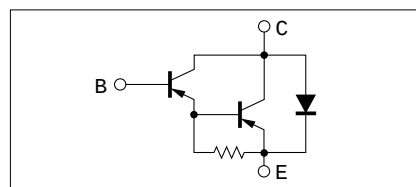
Note) *: Rank classification

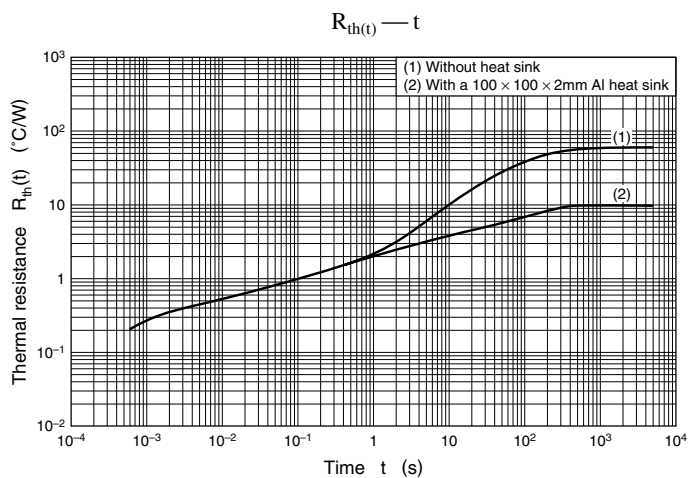
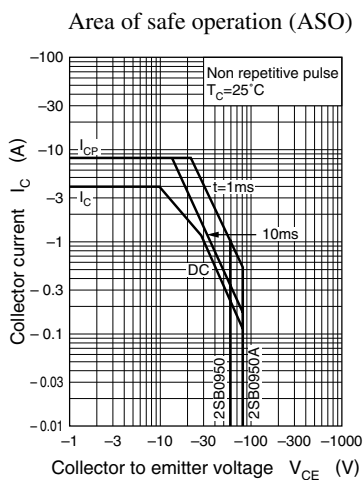
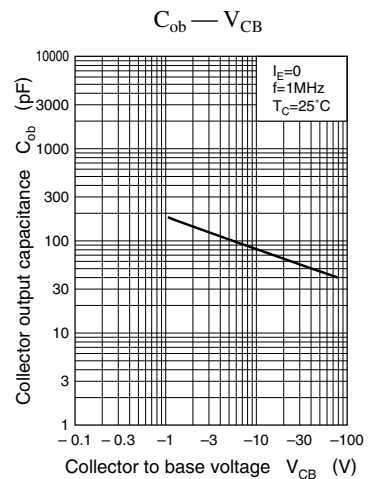
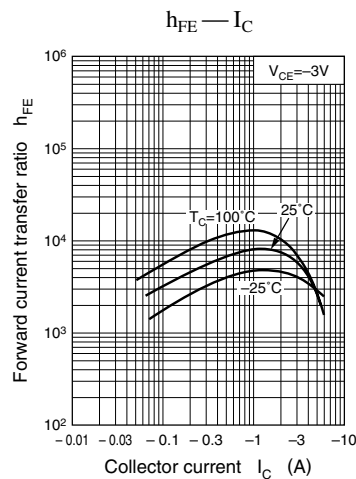
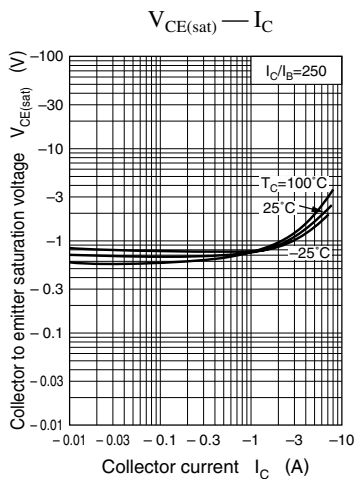
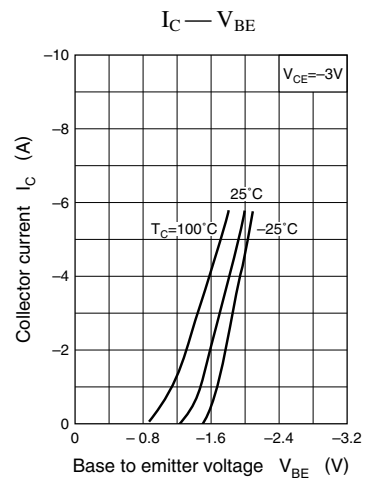
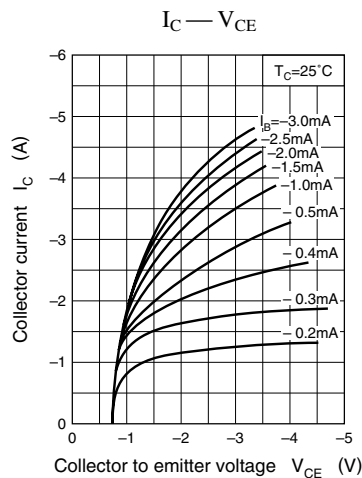
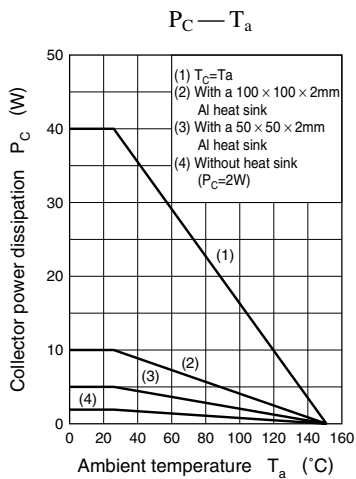
Rank	Q	P
h_{FE2}	2 000 to 5 000	4 000 to 10 000

Note.) The Part numbers in the Parenthesis show conventional part number.



Internal Connection





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